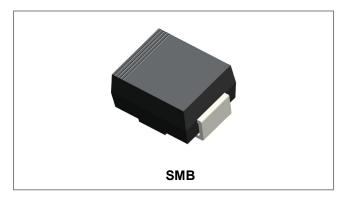






ER2A-ER2J SURFACE MOUNT SUPER FAST RECTIFIER



Features

- Glass Passivated Die Construction
- Ideally Suited for Automatic Assembly
- Low Forward Overload Drop, High Efficiency
- Low Power Loss
- Super-Fast Recovery Time
- Plastic Case Material has UL Flammability Classification Rating 94V-O
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

Circuit Diagram



Mechanical Data

- Case: Low Profile Molded Plastic
- Terminals: Solder Plated, Solderable per MIL-STD-750, Method 2026
- Polarity: Cathode Band or Cathode Notch
- Marking: Type Number
- Weight: 0.09grams(approx)

Maximum Ratings and Electrical Characteristics @TA=25°C unless otherwise specified

Characteristic	Symbol	ER2A	ER2B	ER2C	ER2D	ER2E	ER2G	ER2J	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	150	200	300	400	600	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	105	140	210	280	420	
Average Rectified Output Current @T _L =110°C	lo	2.0			Α				
Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	50			А				
Forward Voltage @I _F = 2.0A, T _J =25°C	V _F	0.95 1.25 1.7		1.7	V				
Maximum DC reverse current $T_A = 25^{\circ}C$ at rated DC blocking voltage $T_A = 125^{\circ}C$	I _R	5.0 100			μA				
Typical junction capacitance (Note 1)	Сл	25		pF					
Maximum Reverse Recovery Time (Note 2)	Trr	35			ns				
Typical thermal resistance (Note 3)	R _{0JL}	20			°C/W				
Operating junction and storage temperature range	T _J ,T _{STG}	-65 to +150		°C					

Note: 1. Measured at 1.0 MHZ and applied reverse voltage of 4.0 V_{DC}

- 2. Measured with I_F =0.5A, I_R =1.0A, I_{rr} =0.25A,
- 3. Mounted on P.C. Board with 8.0mm² lead area







Ratings and Characteristics Curves

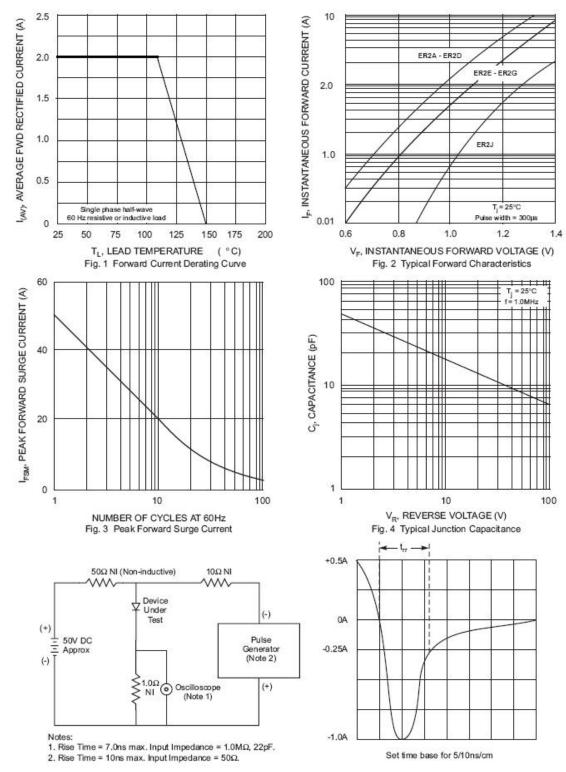


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

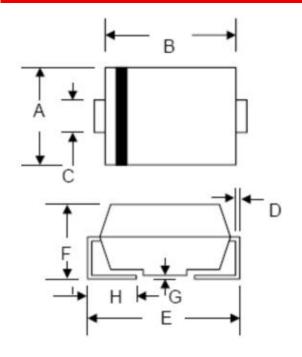
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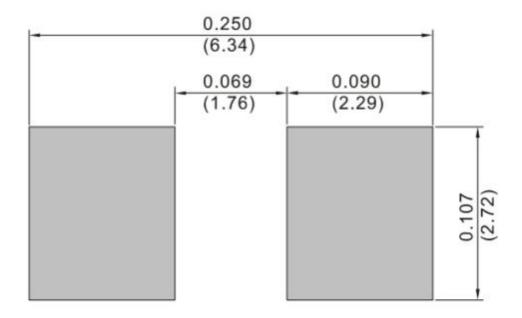


Mechanical Dimensions SMB



CYMPOL	Milli	meters	Inches		
STWBOL	SYMBOL Min. Max.		Min.	Max.	
Α	3.30	3.94	0.130	0.155	
В	4.06	4.70	0.160	0.185	
С	1.80	2.20	0.071	0.087	
D	0.152	0.305	0.006	0.012	
E	4.80	5.59	0.189	0.220	
F	2.10	2.60	0.083	0.102	
G	0.051	0.203	0.002	0.008	
н	0.76	1.52	0.030	0.060	

Suggested Solder Pad Layout (Millimeters/Inches)



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Ordering Information

Device	Package	Shipping
ER2A-ER2J	SMB (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram

Where XXXXX is YYWWL



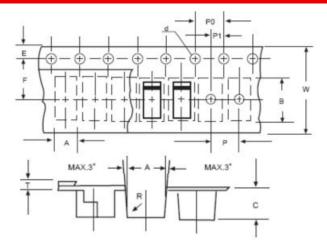
ER = Device Type 2 = Forward Current (2A) A = Reverse Voltage (50V) YY = Year

WW = Week
L = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

Carrier Tape Specification SMB



SYMBOL	Millimeters			
STIMBUL	Min.	Max.		
Α	2.97	3.17		
В	5.70	5.90		
С	2.32	2.52		
d	1.40	1.60		
E	1.40	1.60		
F	5.60	5.70		
Р	3.90	4.10		
P0	3.90	4.10		
P1	1.90	2.10		
Т	0.25	0.35		
W	11.80	12.20		







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